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# 5.1 Fully Integrated Isolated DC-to-DC Converter and Half Bridge Gate Driver with Integral Power Supply

1<sup>st</sup> International Workshop on Power Supply on Chip Cork, Ireland



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#### Outline

- Integrated Signal and Power Isolation Needs
- Power Converter Architecture
- Transformer Structure
- Converter Performance
- Half Bridge Gate Driver Architecture
- Summary



**Isolation Applications** 

PLC I/O and Communication



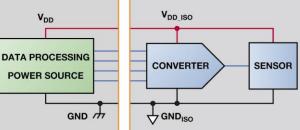
#### **Power Supply**



Instrumentation Data Acquisition and Communication



Motor Control Sensing and Gate Drive







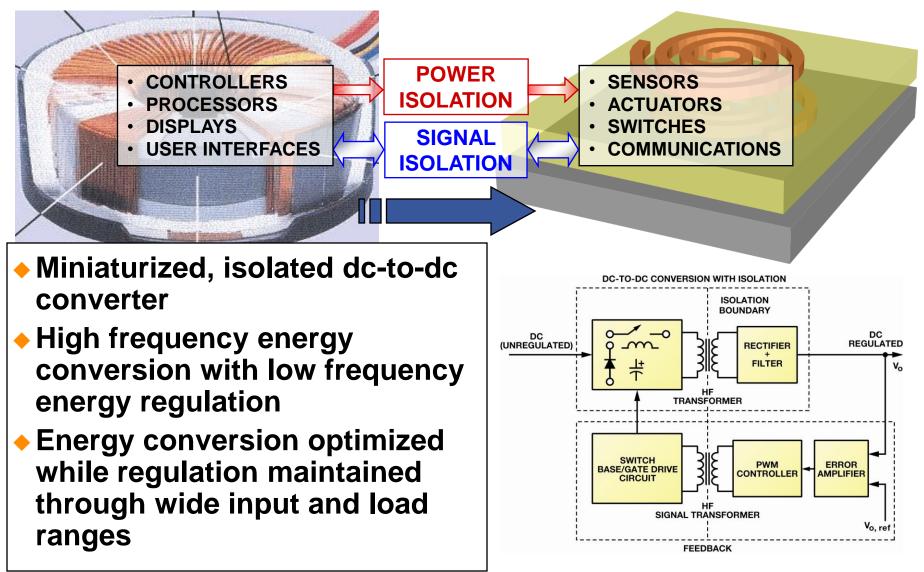


Patient Monitoring To/From Patient



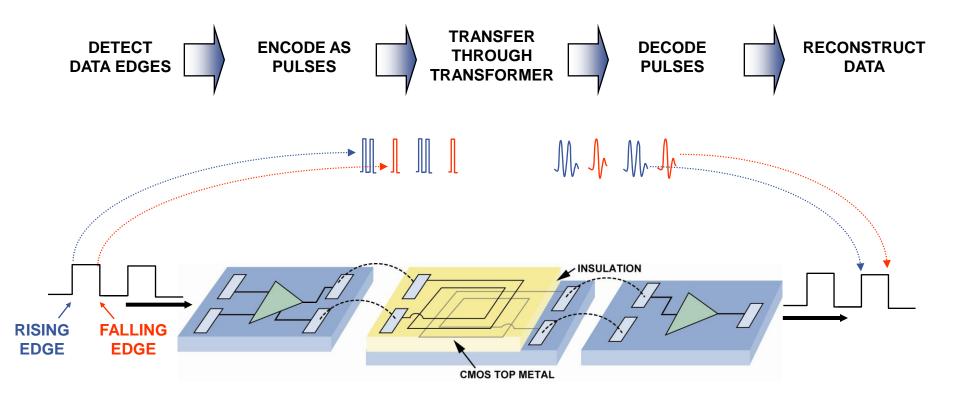


#### **Integrated Isolated Power Transfer Needs**



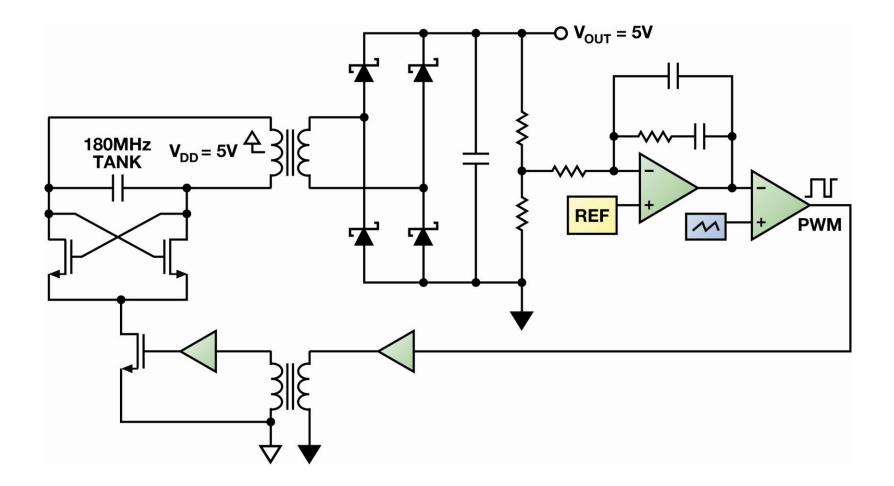


## **Signal Transmission Operational Diagram**



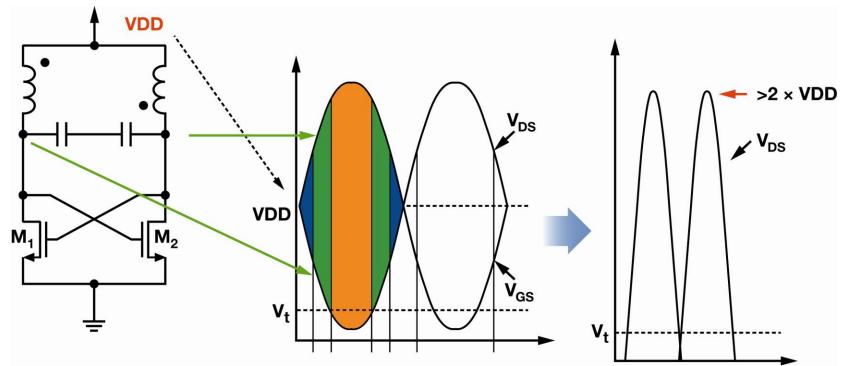


#### **DC-to-DC Converter Architecture**





#### **Primary Switching States: Resonant Gate Drive ZVS**



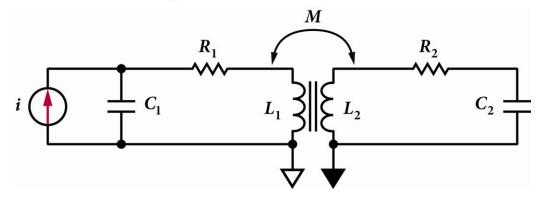
V1 = VDD + V<sub>1</sub>Cos(ωt). Region I: V<sub>1</sub> < V<sub>t</sub>/2 both saturated.

Region II:  $V_t/2 < V_1 < VDD - V_t$  one linear, and one saturated. Region III: VDD -  $V_t < V_1$  one linear, and the other will be off. We want region III! Power delivered to load, not MN1/MN2!!!



#### **Transformer-Coupled Resonator**

**High Q Resonance** 



$$\omega_{1,2}^{2}\Big|^{Transf} = \frac{-(L_{1}C_{1} + L_{2}C_{2}) \pm \sqrt{(L_{2}C_{2} + L_{1}C_{1})^{2} + 4C_{1}C_{2}(M^{2} - L_{1}L_{2})}}{2C_{1}C_{2}(M^{2} - L_{1}L_{2})}$$

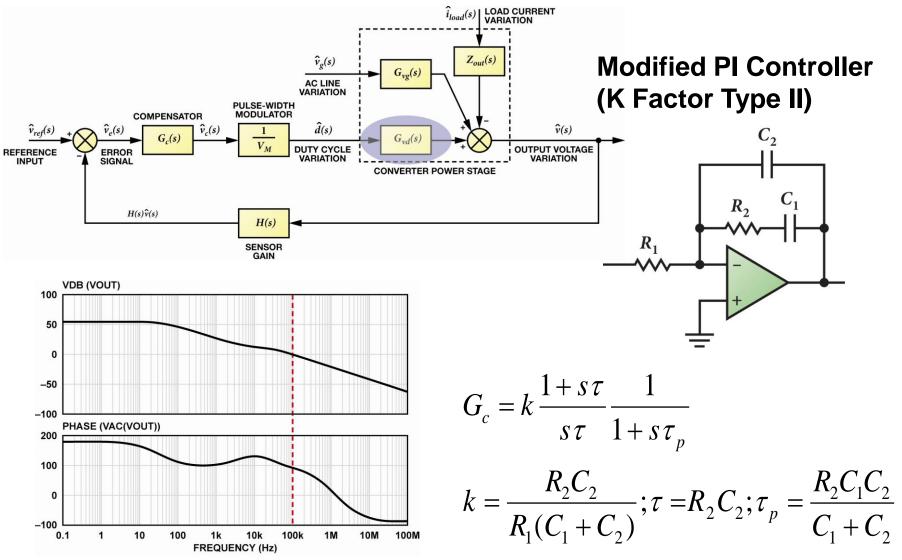
$$\omega_1^2\Big|^{Transf} = \frac{1}{(L+M)C} \qquad \qquad \omega_2^2\Big|^{Transf} = \frac{1}{(L-M)C}$$

 $Z_{in}(\omega_1)\Big|^{Transf} \approx \frac{L+M}{2rC} \qquad Z_{in}(\omega_2)\Big|^{Transf} \approx \frac{L-M}{2rC}$ 

Low Q Resonance

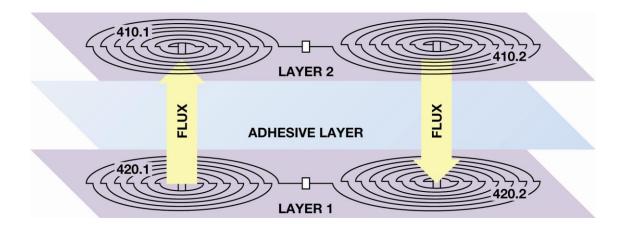


## **Converter Stability**



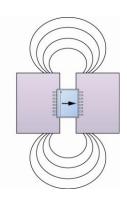


#### **Power Transformer Radiation Minimized Through Antiphase Center Tap**



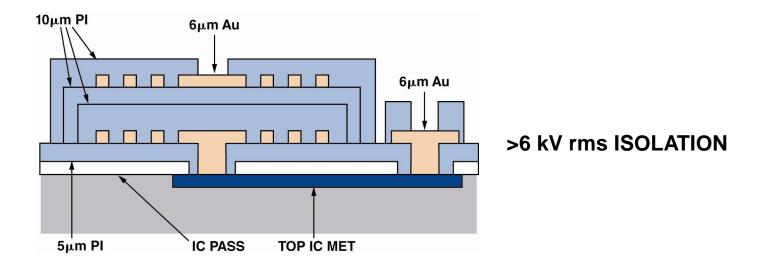
#### **PCB Radiation Dominant-PCB Techniques Available**







#### **Transformer Structures**

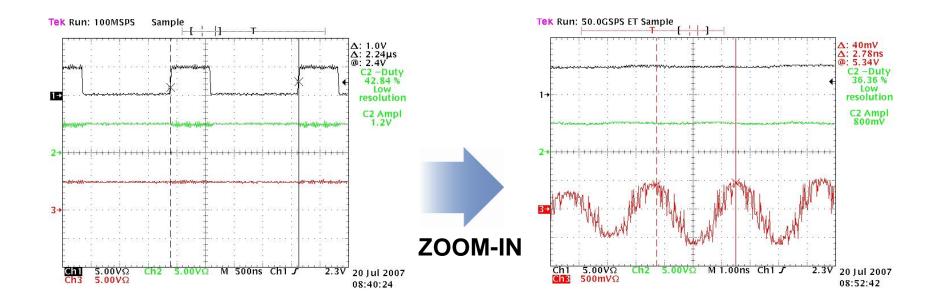


Primary: Two Coils Connected in Center-Tapped

- L = 8 nH, R = 0.8 Ω, Cs = 0.38 pF, Q = 19 at 300 MHz
- Radius = 460  $\mu$ m, Turns = 3, Width = 60  $\mu$ m, Space = 7  $\mu$ m
- Secondary (1:1 for 5 V output): Two Coils Connected in Center-Tapped
- L = 8 nH, R = 0.8 Ω, Cs = 1.2 pF, Q = 13 at 300 MHz
- Radius = 460  $\mu$ m, Turns = 3, Width = 60  $\mu$ m, Space = 7  $\mu$ m



### **Converter Waveforms**

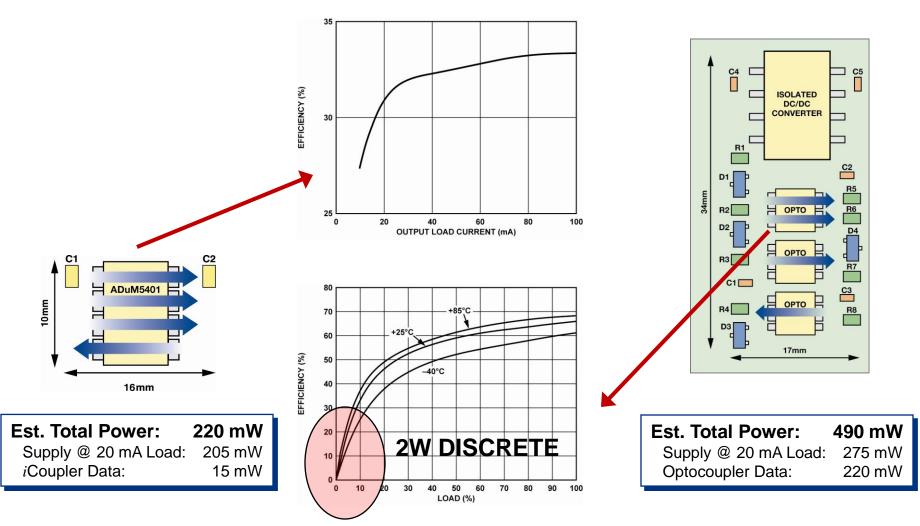


Ch. 1 is the 450 kHz PWM signal.Ch. 2 is the input supply.Ch. 3 is the isolated supply output.

340 MHz Noise => 170 MHz Tank

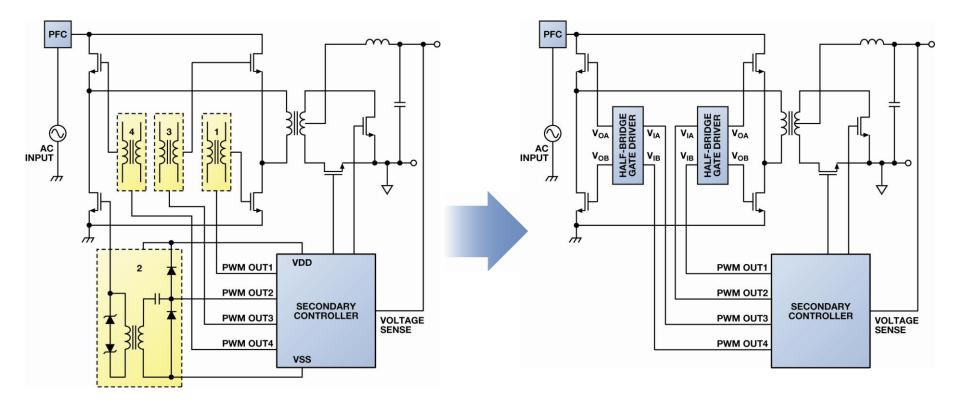


### **Converter Performance: Saving Power Compared to Discrete Solution**





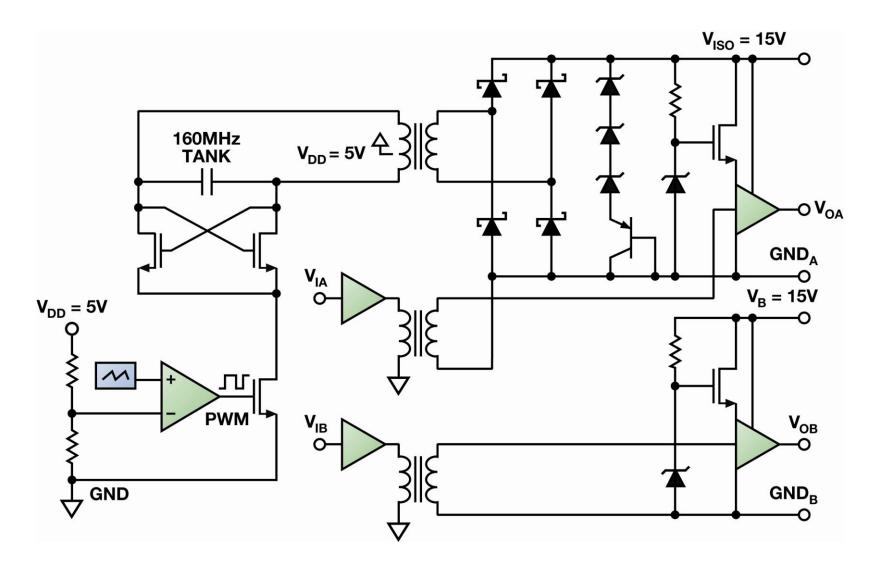
#### **Isolated Gate Drive Integration Needs**



Size Reduction, Ease of Use, and Elimination of Duty-Cycle Limitation

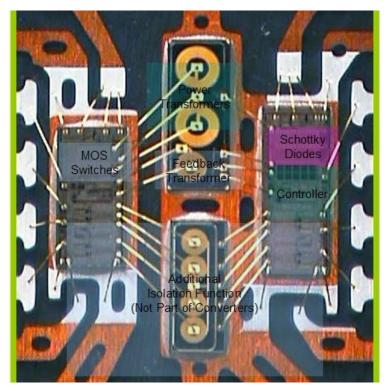


**Half-Bridge Gate Driver Architecture** 

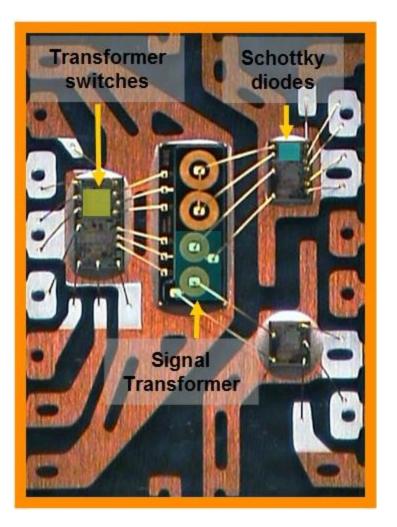




## 500 mW DC-to-DC Converter and Half-Bridge Gate Driver in 16-Lead SOIC



#### 4-Channel Isolation Integrated





## **Summary**

 500 mW, 33% efficient integrated isolated DC-to-DC converter architecture was reviewed.

 The integrated signal and power integration provide possibilities for total isolated system integration; reduces total system cost and complexity.

Acknowledgement of contribution and assistance from ADI iCoupler group members

